SQS140ENW

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Vishay Siliconix

RoHS

COMPLIANT HALOGEN

FREE

Automotive N-Channel 40 V (D-S) 175 °C MOSFET

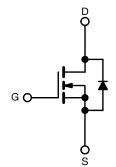


Marking code: Q042

PRODUCT SUMMARY		
V _{DS} (V)	40	
$R_{DS(on)} (\Omega)$ at $V_{GS} = 10 V$	0.00253	
I _D (A) ^e	152	
Configuration	Single	

FEATURES

- TrenchFET[®] Gen IV power MOSFET
- AEC-Q101 qualified
- 100 % R_g and UIS tested
- Wettable flank terminals
- Low thermal resistance with 0.75 mm profile
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



N-Channel MOSFET

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1.26

ORDERING INFORMATION			
Package	PowerPAK [®] 1212-8SLW		
Lead (Pb)-free and halogen-free	SQS140ENW (for detailed order number please see <u>www.vishay.com/doc?79771</u>)		

PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	40	V	
Gate-source voltage		V _{GS}	± 20	v	
Continuous drain current ^e	T _C = 25 °C	I	152		
	T _C = 125 °C	Ι _D	87		
Continuous source current (diode conduction) ^e		I _S	108	А	
Pulsed drain current ^{a, e}		I _{DM}	350		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	31.5		
Single pulse avalanche energy	L = 0.1 MH	E _{AS}	49.6	mJ	
	T _C = 25 °C	D	119	14/	
Maximum power dissipation ^{a, e}	T _C = 125 °C	P _D	39	W	
Operating junction and storage temperature	range	T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) ^c		-	260	C	
THERMAL RESISTANCE RATIN	GS				
PARAMETER		SYMBOL	LIMIT	UNIT	

PARAMETER Junction-to-ambient

Junction-to-case (drain) d

Notes

- a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %
- b. When mounted on 1" square PCB (FR4 material)
- c. See solder profile (www.vishay.com/doc?73257). A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection

R_{thJA}

R_{thJC}

PCB mount b

- d. As per JESD51-14
- e. Values based on RthJC and TC of 25 °C. Actual values achievable will be dependent on the thermal characteristics of the complete system

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PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static							
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0, I_D = 250 \ \mu A \qquad 40$ $V_{DS} = V_{GS}, I_D = 250 \ \mu A \qquad 2.5$		40	-	-	v
Gate-source threshold voltage	V _{GS(th)}			2.5	3.0	3.5	v
Gate-source leakage	I _{GSS}	V _{DS} =	$= 0 \text{ V}, \text{ V}_{\text{GS}} = \pm 20 \text{ V}$	-	-	± 100	nA
		$V_{GS} = 0 V$	V _{DS} = 40 V	-	-	1	
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	$V_{DS} = 40 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	50	μA
		$V_{GS} = 0 V$	$V_{DS} = 40 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	150	
On-state drain current ^a	I _{D(on)}	V _{GS} = 10 V	$V_{DS} \ge 5 V$	20	-	-	А
		V _{GS} = 10 V	I _D = 10 A	-	0.0021	0.00253	
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V	I _D = 10 A, T _J = 125 °C	-	-	0.0038	Ω
		V _{GS} = 10 V	I _D = 10 A, T _J = 175 °C	-	-	0.0043	
Forward transconductance b	9 _{fs}	V _{DS}	= 15 V, I _D = 10 A	-	55	-	S
Dynamic ^b		•					
Input capacitance	C _{iss}		0 V V _{DS} = 25 V, f = 1 MHz	-	2222	3111	pF
Output capacitance	C _{oss}	$V_{GS} = 0 V$		-	923	1295	
Reverse transfer capacitance	C _{rss}			-	37	52	
Total gate charge ^c	Qg			-	38	57	nC
Gate-source charge ^c	Q _{gs}	V _{GS} = 10 V	$V_{DS} = 20 V, I_D = 5 A$	-	11	-	
Gate-drain charge ^c	Q _{gd}			-	8	-	
Gate resistance	R _g		f = 1 MHz	0.5	1.1	1.7	Ω
Turn-on delay time ^c	t _{d(on)}			-	13	20	
Rise time ^c	t _r	$\label{eq:VDD} \begin{array}{l} V_{DD} = 20 \ V, \ R_{L} = 1.33 \ \Omega \\ I_{D} \cong 15 \ A, \ V_{GEN} = 10 \ V, \ R_{g} = 1 \ \Omega \end{array}$		-	5	9	
Turn-off delay time ^c	t _{d(off)}			-	22	33	ns
Fall time ^c	t _f			-	8	12	
Source-Drain Diode Ratings and Charac	teristic ^b	•			•		
Pulsed current ^a	I _{SM}			-	-	350	Α
Forward voltage	V_{SD}	I _F =	= 10 A, V _{GS} = 0 V	-	0.82	1.1	V
Body diode reverse recovery time	t _{rr}	I _F = 5 A, di/dt = 100 A/μs		-	38	78	ns
Body diode reverse recovery charge	Q _{rr}			-	34	70	nC
Reverse recovery fall time	ta			-	19	-	
Reverse recovery rise time	t _b			-	20	-	ns
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.6	-3.2	А

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

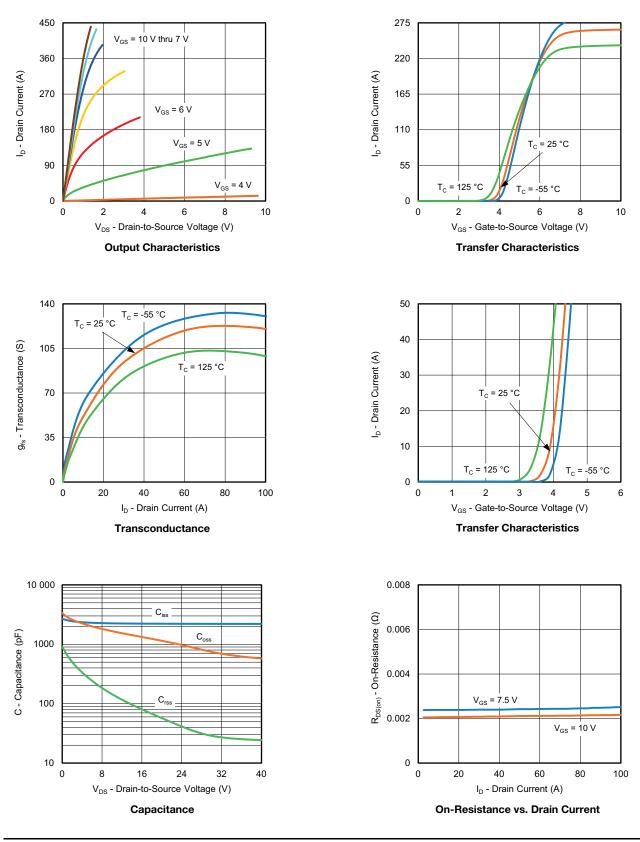
c. Independent of operating temperature

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



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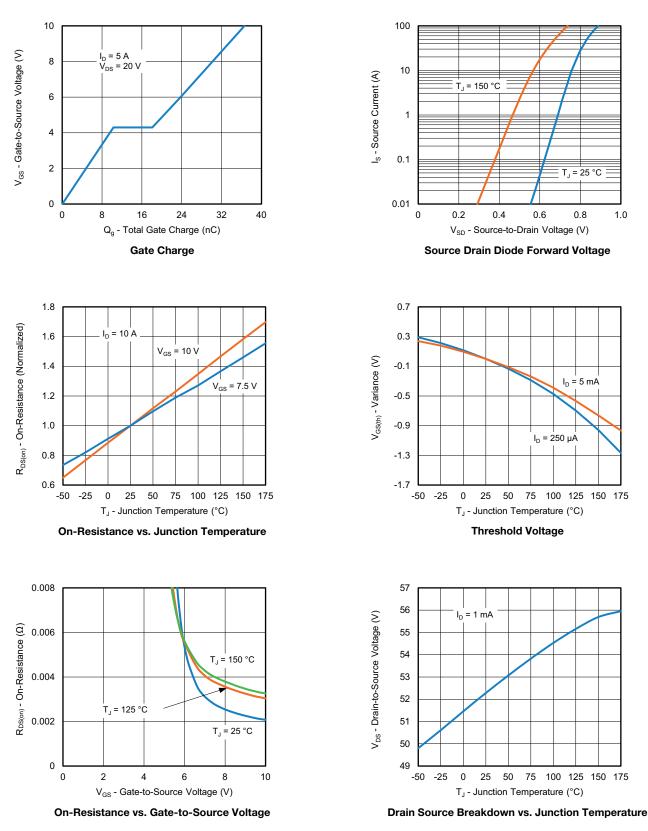
T_J = 25 °C

0.8

 $I_D = 5 \text{ mA}$

1.0

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



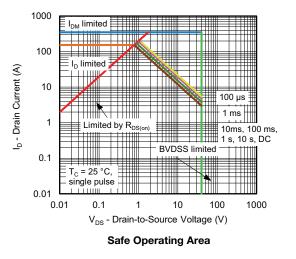
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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)

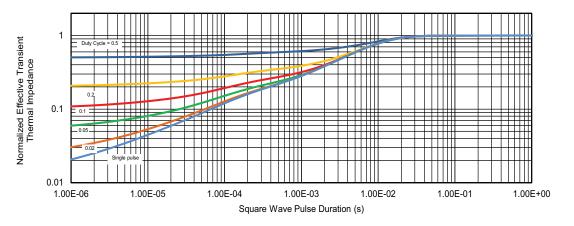


Note

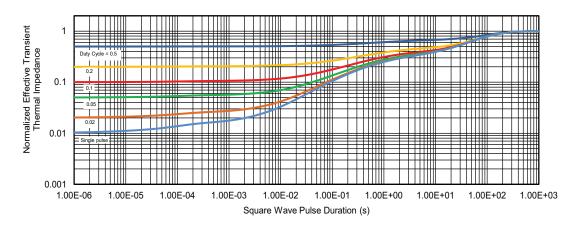
a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

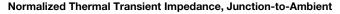


THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case





Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

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RECOMMENDED MINIMUM PADS FOR PowerPAK[®] 1212-8 Single



Recommended Minimum Pads Dimensions in Inches/(mm)

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